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SEMICONDUCTOR PHYSICS

- 072001** First-principles study of the electronic structures and optical properties of C–F–Be doped wurtzite ZnO (6 pages)
Zuo Chunying, Wen Jing, and Zhong Cheng

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Zhou Maoxiu, Zhao Qiang, Zhang Wei, Liu Qi, and Dai Yuehua

SEMICONDUCTOR MATERIALS

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Kh. S. Karimov, M. Saleem, Z. M. Karieva, A. Mateen, M. Tariq Saeed Chani, and Q. Zafar
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Tao Zhikuo, Zhang Rong, Xiu Xiangqian, Cui Xugao, Li Li, Li Xin, Xie ZiLi, Zheng Youdou, Zheng Rongkun, and Simon P Ringer
- 073003** Structural and optical properties of Zn-doped β -Ga₂O₃ films (4 pages)
Yue Wei, Yan Jinliang, Wu Jiangyan, and Zhang Liying

SEMICONDUCTOR DEVICES

- 074001** Fabrication and characterization of a low frequency electromagnetic energy harvester (5 pages)
Abu Riduan Md. Foisal and Gwiy-Sang Chung
- 074002** A different approach for determining the responsivity of n⁺p detectors using scanning electron microscopy (5 pages)
Omeime Xerviar Esebamen, Göran Thungström, and Hans-Erik Nilsson
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Zhang Xianjun, Yang Yintang, Chai Changchun, Duan Baoxing, Song Kun, and Chen Bin
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Zhong Yinghui, Wang Xiantai, Su Yongbo, Cao Yuxiong, Jin Zhi, Zhang Yuming, and Liu Xinyu
- 074005** A low on-resistance SOI LDMOS using a trench gate and a recessed drain (4 pages)
Ge Rui, Luo Xiaorong, Jiang Yongheng, Zhou Kun, Wang Pei, Wang Qi, Wang Yuangang, Zhang Bo, and Li Zhaoji
- 074006** Universal trench design method for a high-voltage SOI trench LDMOS (4 pages)
Hu Xiarong, Zhang Bo, Luo Xiaorong, and Li Zhaoji
- 074007** Giant magnetoresistance in a two-dimensional electron gas modulated by ferromagnetic and Schottky metal stripes (5 pages)
Lu Jianduo and Xu Bin

(Continued on inside back cover)

- 074008 Enhanced light output power in InGaN/GaN light-emitting diodes with a high reflective current blocking layer (4 pages)**

Zhang Xiaojie, Yang Ruixia, and Wang Jinghui

- 074009 Investigation of the polysilicon p-i-n diode and diode string as a process compatible and portable ESD protection device (5 pages)**

Jiang Yibo, Du Huan, and Han Zhengsheng

- 074010 Design and fabrication of an InP arrayed waveguide grating for monolithic PICs (4 pages)**

Pan Pan, An Junming, Wang Liangliang, Wu Yuanda, Wang Yue, and Hu Xiongwei

SEMICONDUCTOR INTEGRATED CIRCUITS

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Zhou Chunyuan, Zhang Lei, and Qian He

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Wang Junqian, Yang Haifeng, Wei Rui, Xu Jun, and Ren Junyan

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Gao Haijun, Sun Lingling, Kuang Xiaofei, and Lou Liheng

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Liang Yaping, Che Dazhi, Liang Cheng, and Sun Lingling

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Xu Yang, Chi Baoyong, Xu Yang, Qi Nan, and Wang Zhihua

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Zhao Bohua, Huang Ran, Bu Jianhui, Lü Yinxue, Wang Yiqi, Ma Fei, Xie Guohua, Zhang Zhensong, Du Huan, Luo Jiajun, Han Zhengsheng, and Zhao Yi

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Ding Lili, Yao Zhibin, Guo Hongxia, Chen Wei, and Fan Ruyu

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Gu Gaowei, Zhu En, Lin Ye, and Liu Wensong